



IEC 62716:2013

Ammonia corrosion testing of photovoltaic (PV) modules

Confirmation of test results

Ref.: 10036/2021-40357

Applicant: LG Electronics Inc.
168, Suchul-daero, Gumi-si, Gyeongsangbuk-do,
730-903, South Korea

Product: Crystalline Silicon Photovoltaic (PV)-Modules

Type: A) LGXXN3C-V6
B) LGXXN3W-V6
C) LGXXN3K-V6

XXX in the type replace the power in Watt and can be any number between: 395 - 415 for A), B) and 390 - 410 for C)

Manufacturer: LG Electronics Inc.

Standard: IEC 62716:2013

Test conditions: As given in IEC 62716:2013

1st test section: Testing time 8 h

NH₃ Concentration: 6667 ppm

Chamber temperature: 60°C

Rel. humidity: 100%

2nd test section: Testing time 16 h

NH₃ Concentration: 0 ppm

Chamber temperature: 25°C

Rel. humidity: 36 %

Total testing time 480 h (20 cycles)



Pass criteria

Visual inspection:	No findings which may affect safety.
Power degradation:	<5 %
Dry Insulation:	>40 MΩm ²
Wet insulation:	>40 MΩm ²
Bonding path resistance:	<0,1 MΩ
Bypass diode functionality test:	Bypass diodes shall remain functional

Summary of test results:

Visual inspection: No findings which affect safety.

Maximum power degradation:	allowed	<5 %
	measured	0,92 %

The measured degradation is below the allowed degradation.

Dry insulation resistance:	required	≥18,2 MΩ
	measured	min. 999 MΩ

The measured dry insulation resistance is above the limit.

Wet insulation resistance:	required	≥18,2 MΩ
	measured	min. 999 MΩ

The measured wet insulation resistance is above the limit.

Bonding path resistance:	required	<0,1 MΩ
	measured	<0,01 MΩ

The measured resistance is below the limit.


Bypass diode functionality test: Bypass diodes remain functional

The complete test results and the related bills of materials are given in the Test Reports No. TRPVM-2021-40357-1.

VDE Renewables GmbH


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